## NSN 5961-01-342-3440

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-342-3440 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.360 inches **End Application:** 2350-01-087-1095 tank, combat, full tracked **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to emitter voltage/static/base open and 80.0 collector to base voltage, dc and 6.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute and 3.5 watts small-signal input power, common-collector preset **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Nuclear hardness process; junction pattern arrangement: npn **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

## **NSN 5961-01-342-3440** Transistor - Page 2 of 2



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